

BT136X-600D

Rev.01 - 16 April 2018

4Q Triac

Product data sheet

1. General description

Planar passivated very sensitive gate four quadrant triac in a SOT186A (TO-220F) plastic package intended for use in general purpose bidirectional switching and phase control applications, where high sensitivity is required in all four quadrants. This very sensitive gate "series D" triac is intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- Very sensitive gate
- Triggering in all four quadrants
- Isolated package
- Direct triggering from low power drivers and logic ICs
- Low holding current for small load currents and lowest EMI at commutation

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

0	Demonstern	O and the second		N/-			11
Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{DRM}	repetitive peak off-state voltage			6	00		V
I _{T(RMS)}	RMS on-state current	full sine wave; T _h ≤ 92 °C; <u>Fig. 1; Fig. 2</u> ; <u>Fig. 3</u>	4			A	
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	25		A		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
I _{GT} gate trigger current	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>		-	2	5	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>		-	2.5	5	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>		-	2.5	5	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>		-	5	10	mA
I _H	holding current	V _D = 12 V; T _i = 25 °C; <u>Fig. 9</u>		-	1.2	10	mA

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1	mb	
2	T2	main terminal 2		Ν
3	G	gate		
mb	n.c.	mounting base; isolated		sym051
			ŲŲŲ	
			1 2 3	

6. Ordering information

Table 3. Ordering inform	nation		
Type number	Package		
	Name	Description	Version
BT136X-600D	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack"	SOT186A

7. Marking

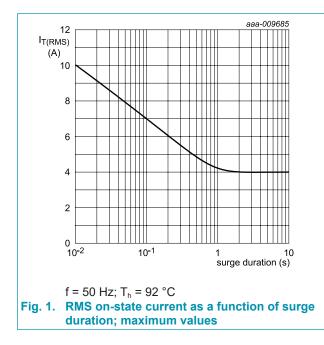
Table 4	. Marking codes	
Type r	number	Marking codes
BT136	3X-600D	BT136X-600D

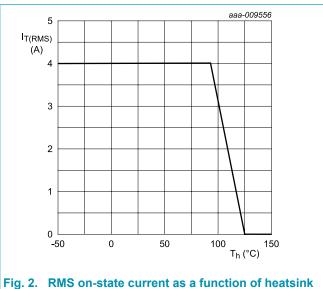
8. Limiting values

Table 5. Limiting values

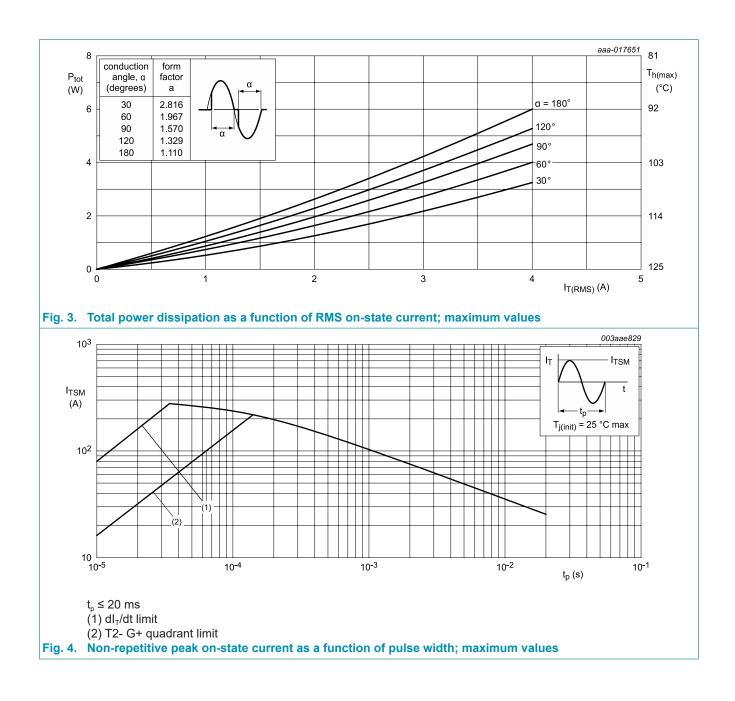
In accordance with the Absolute Maximum Rating System (IEC 60134).

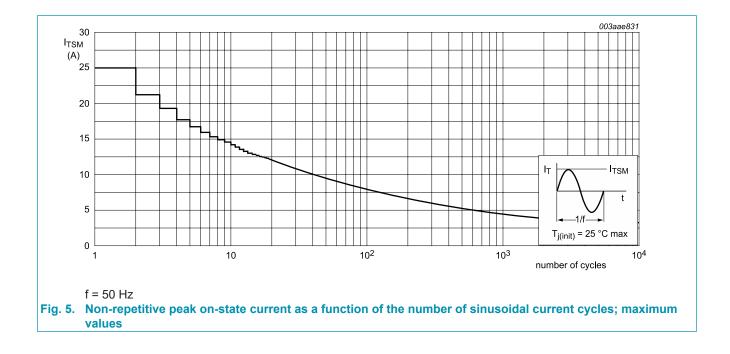
Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		600	V
$\mathbf{I}_{\mathrm{T(RMS)}}$	RMS on-state current	full sine wave; $T_h \le 92 \text{ °C}$; Fig 1; Fig 2; Fig 3	4	А
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5	25	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms	27	А
l ² t	I ² t for fusing	t _P = 10 ms; SIN	3.1	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 10 mA; T2+ G+	50	A/µs
		I _G = 10 mA; T2+ G-	50	A/µs
		I _G = 10 mA; T2- G-	50	A/µs
		I _G = 20 mA; T2- G+	10	A/µs
I _{GM}	peak gate current		2	А
P _{GM}	peak gate power		5	W
P _{G(AV)}	average gate power	over any 20 ms period	0.5	W
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		125	°C





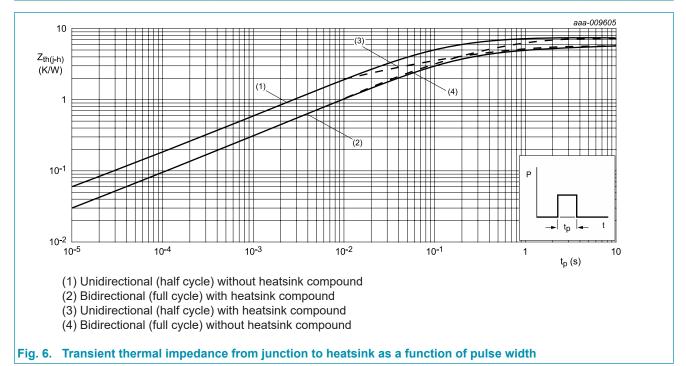
temperature; maximum values





9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-h)}	thermal resistance from junction to	full or half cycle; with heatsink compound; Fig 6	-	-	5.5	K/W
	heatsink	full or half cycle; without heatsink compound; <u>Fig 6</u>	-	-	7.2	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient	in free air	-	55	-	K/W

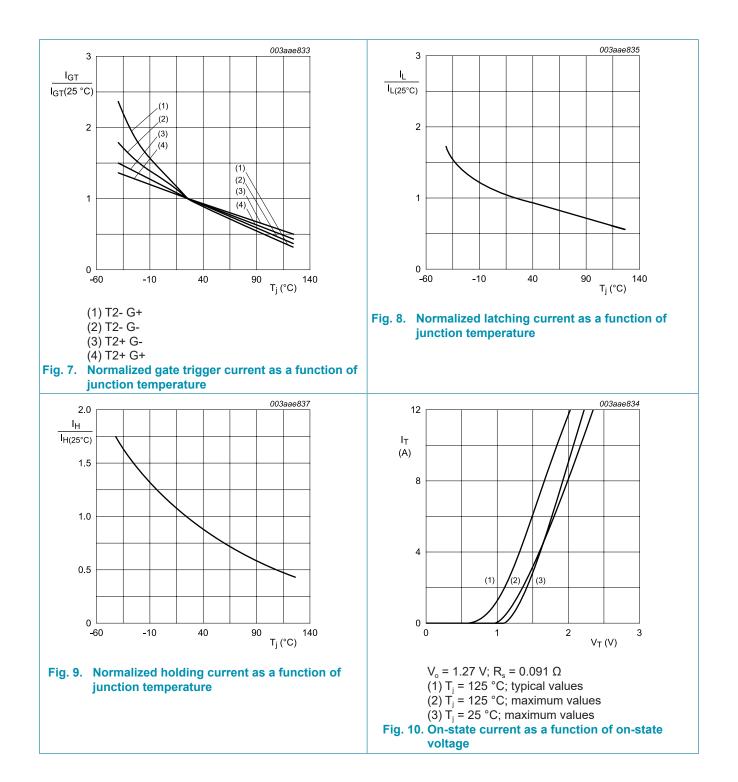


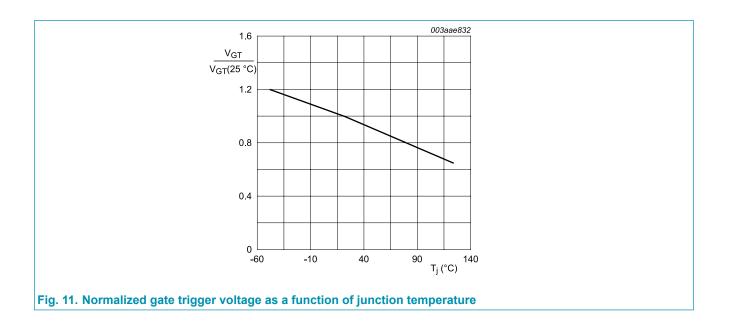
10. Isolation characteristics

Table 7. Iso	lation characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{isol(RMS)}	RMS isolation voltage	from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C	-	-	2500	V
C _{isol}	isolation capacitance	from main terminal 2 to external heatsink; f = 1 MHz; T_h = 25 °C	-	10	-	pF

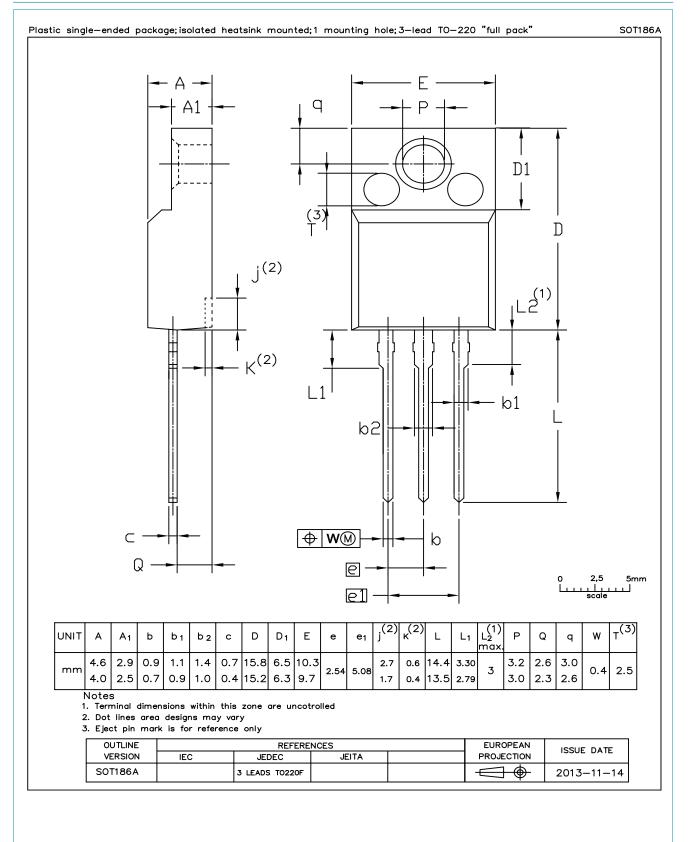
11. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 7	-	2	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 7	-	2.5	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 7	-	2.5	5	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 7	-	5	10	mA
L	latching current	$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2+ G+};$ T _j = 25 °C; Fig. 8	-	1.6	10	mA
		V_{D} = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 8	-	1.2	15	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; Fig. 8	-	2.2	10	mA
		$V_{D} = 12 \text{ V}; \text{ I}_{G} = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; Fig. 8	-	1.2	15	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	1.2	10	mA
V _T	on-state voltage	I _T = 5 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.7	V
V _{GT}	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		$V_{D} = 400 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 125 \text{ °C};$ Fig. 11	0.25	0.4	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics					_
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ R}_{GK} = 1k\Omega;$ ($V_{DM} = 67\% \text{ of } V_{DRM}$); exponential waveform; gate open circuit	-	5	-	V/µs
t _{gt}	gate-controlled turn-on time	$V_{\rm D}$ = 600 V; I _{TM} = 6 A; I _G = 0.1 A; dI _G /dt = 5 A/µs	-	2	-	μs
	time	dI _G /dt = 5 A/µs				





12. Package outline



13. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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